

STN83003

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Very high switching speed

Application

■ Electronics ballasts for fluorescent lighting

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The STN83003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the STN93003, its complementary PNP transistor.

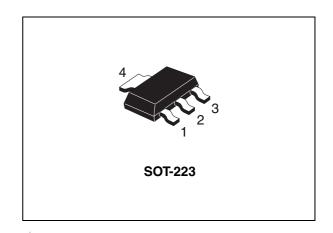


Figure 1. Internal schematic diagram

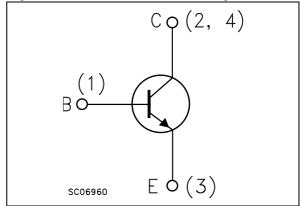


Table 1. Device summary

| Part number | Marking | Package | Packaging |
|-------------|---------|---------|---------------|
| STN83003 | N83003 | SOT-223 | Tape and reel |

Contents STN83003

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STN83003 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|------------------|---|----------------------|------|
| V _{CES} | Collector-emitter voltage (V _{BE} = 0) | 700 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | 400 | ٧ |
| V _{EBO} | Emitter-base voltage $(I_C = 0, I_B = 0.75 \text{ A}, t_P < 10 \text{ µs})$ | V _{(BR)EBO} | V |
| I _C | Collector current | 1.5 | Α |
| I _{CM} | Collector peak current (t _P < 5 ms) | 3 | Α |
| I _B | Base current | 0.75 | Α |
| I _{BM} | Base peak current (t _P < 5 ms) | 1.5 | Α |
| P _{TOT} | Total dissipation at T _a = 25 °C | 1.6 | W |
| T _{STG} | Storage temperature | -65 to 150 | °C |
| TJ | Max. operating junction temperature | 150 | °C |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|-------------------|---|-------|------|
| R _{thJA} | Thermal resistance junction-ambient (1) max | 78 | °C/W |

^{1.} Device mounted on PCB area of 1 cm².

Electrical characteristics STN83003

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

| Symbol | Parameter | Test condi | tions | Min. | Тур. | Max. | Unit |
|--------------------------|---|--|--|---------------|------|----------|----------|
| I _{CES} | Collector cut-off current (V _{BE} = 0) | V _{CE} = 700 V V _{CE} = 700 V | T _C = 125 °C | | | 1 5 | mA mA |
| V _{(BR)EBO} | Emitter-base breakdown voltage (I _C = 0) | I _E = 10 mA | | 12 | | 18 | ٧ |
| V _{CE(sus)} (1) | Collector-emitter sustaining voltage (I _B = 0) | I _C = 10 mA | | 400 | | | ٧ |
| V _{CE(sat)} (1) | Collector-emitter saturation voltage | $I_C = 0.35 A$ $I_C = 0.5 A$ | $I_B = 50 \text{ mA}$ $I_B = 0.1 \text{ A}$ | | | 1 0.5 | V V |
| V _{BE(sat)} (1) | Base-emitter saturation voltage | I _C = 0.5 A | I _B = 0.1 A | | | 1 | V |
| h _{FE} | DC current gain | $I_C = 10 \text{ mA}$ $I_C = 0.35 \text{ A}$ $I_C = 1 \text{ A}$ | $V_{CE} = 5 V$ $V_{CE} = 5 V$ $V_{CE} = 5 V$ | 10 16 4 | 25 | 32 | |
| | Resistive load | | | | | | |
| t _r | Rise time | $I_C = 0.35 A$ | $V_{CC} = 125 \text{ V}$ | | 100 | | ns |
| t _s | Storage time | $I_{B1} = -I_{B2} = 70 \text{ mA}$ | | 1.5 | 2.2 | 2.9 | μs |
| t _f | Fall time | $t_P \ge 25 \ \mu s$ | | | 0.2 | | μs |
| | Inductive load | $I_C = 0.5 A$ | $I_{B1} = 0.1 A$ | | | | |
| t _s | Storage time | $V_{BE(off)} = -5 V$ | L = 10 mH | | 450 | | ns |
| t _f | Fall time | V _{Clamp} = 300 V | | | 90 | | ns |

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

AM09298v1

Ic MAX PULSED PULSE OPERATION*

10 10 10 10 10 VCE (V)

Figure 3. Derating curve

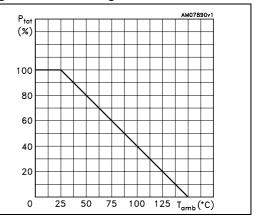


Figure 4. DC current gain $(V_{CE} = 5 V)$

h FE

10²

10¹

T_J =125 °C

 $V_{CE} = 5V$

0670

Figure 5. DC current gain $(V_{CE} = 1 V)$

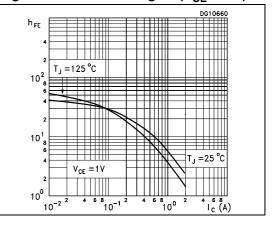


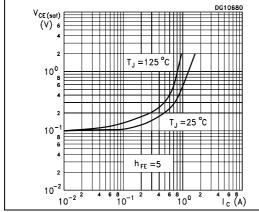
Figure 6. Collector-emitter saturation voltage

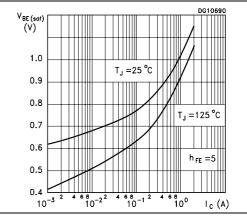
810°

8 10⁻¹

tion Figure 7.

Base-emitter saturation voltage

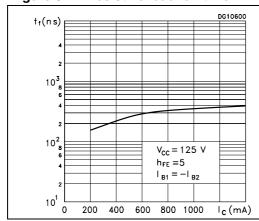




Electrical characteristics STN83003

Figure 8. Resistive load fall time

Figure 9. Resistive load storage time



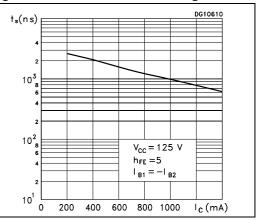
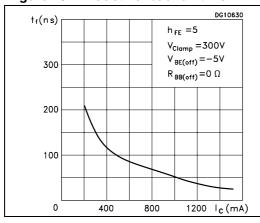


Figure 10. Inductive load fall time

Figure 11. Inductive load storage time



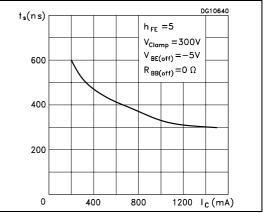
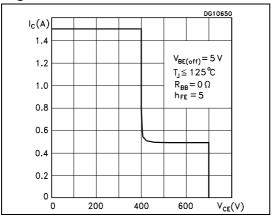
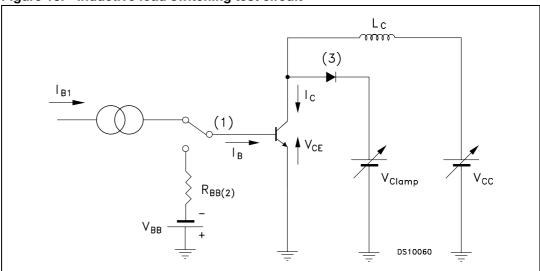


Figure 12. Reverse biased SOA



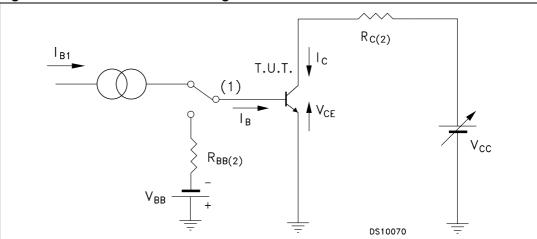
2.2 Test circuits

Figure 13. Inductive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

Figure 14. Resistive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor

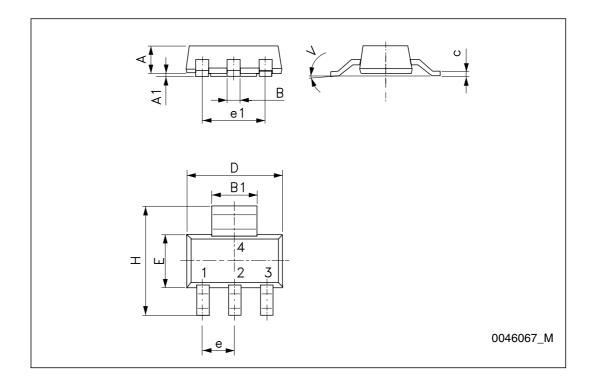
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

8/11 Doc ID 12325 Rev 3

SOT-223 mechanical data

| Dim. | mm. | | | |
|------|------|------|------|--|
| | Min. | Тур. | Max. | |
| Α | | | 1.80 | |
| A1 | 0.02 | | 0.1 | |
| В | 0.60 | 0.70 | 0.85 | |
| B1 | 2.90 | 3.00 | 3.15 | |
| С | 0.24 | 0.26 | 0.35 | |
| D | 6.30 | 6.50 | 6.70 | |
| е | | 2.30 | | |
| e1 | | 4.60 | | |
| E | 3.30 | 3.50 | 3.70 | |
| Н | 6.70 | 7.00 | 7.30 | |
| V | | | 10 ° | |



Revision history STN83003

4 Revision history

Table 5. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 09-May-2006 | 1 | Initial release. |
| 17-Jan-2007 | 2 | The device's safe operating area curve has been added on page 5. |
| 13-Dec-2010 | 3 | Updated package mechanical data on page 9. |

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